

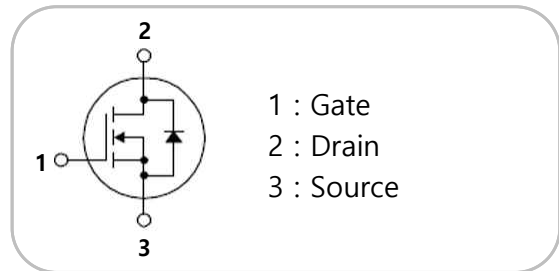
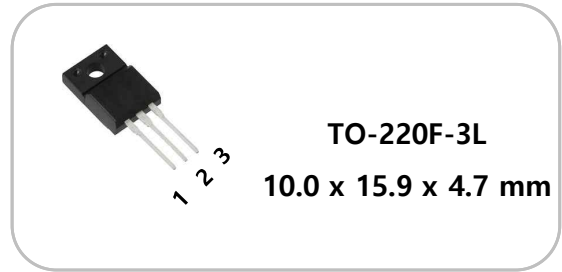
General description

| Symbol | Value |
|------------------------------------|------------|
| V_{DSS} @ $T_C=25^\circ\text{C}$ | Min 500V |
| I_D @ $T_C=25^\circ\text{C}$ | 8.0A |
| $R_{DS(on)}$ | Max 0.8Ω |
| Q_G | Typ 26.0nC |

Features

- Gate Charge(Typ. $Q_G=26.0\text{nC}$)
- High Voltage (Min. $V_{DSS}=500\text{V}$)
- 100% Avalanche Tested

Package



Maximum Ratings ($T_C = 25^\circ\text{C}$)

| Parameter | Symbol | Test Condition | Value | Units |
|--------------------------------|-----------|--|------------|------------------|
| Drain-source voltage | V_{DSS} | $V_{GS}=0\text{V}$, $I_D=250\mu\text{A}$ | 500 | V |
| Drain current (DC) | I_D | $T_C=25^\circ\text{C}$ | 8.00 | A |
| | | $T_C=100^\circ\text{C}$ | 4.5 | A |
| Drain current (Pulsed) | I_{DM} | Pulse width limited by junction temperature | 32 | A |
| Gate-source voltage | V_{GS} | - | ± 30 | V |
| Single pulsed avalanche energy | E_{AS} | $I_{AS}=8.0\text{A}$, $R_G=25\Omega$, $V_{DD}=50\text{V}$, $L=10.2\text{mH}$ | 360 | mJ |
| Power dissipation | P_D | $T_C=25^\circ\text{C}$ | 40 | W |
| Operating junction | T_j | - | -55 to 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | - | -55 to 150 | $^\circ\text{C}$ |




Electrical Characteristics ($T_j = 25^\circ\text{C}$)

| Parameter | Symbol | Test Condition | | | | Units |
|----------------------------------|---------------|---------------------------------------|-----|------|-----------|----------|
| | | | Min | Typ | Max | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $V_{GS}=0V, I_D=250\mu A$ | 500 | - | - | V |
| Zero gate voltage drain current | I_{DSS} | $V_{DS}=500V, V_{GS}=0V$ | - | - | 1.0 | μA |
| Gate-source leakage current | I_{GSS} | $V_{GS}=\pm 30V, V_{DS}=0V$ | - | - | ± 100 | nA |
| Gate threshold voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 2.0 | - | 4.0 | V |
| Drain-source on-state resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=4.0A$ | - | 0.68 | 0.8 | Ω |
| Input capacitance | C_{iss} | $V_{DS}=25V, V_{GS}=0V, f=1MHz$ | - | 1216 | 1520 | pF |
| Output capacitance | C_{oss} | | - | 119 | 149 | |
| Reverse transfer capacitance | C_{rss} | | - | 23 | 29 | |
| Total gate charge | Q_G | $V_{DS}=200V, V_{GS}=10V, I_D=8.0A$ | - | 26.0 | 32.0 | nC |
| Gate-source charge | Q_{GS} | | - | 7.7 | - | |
| Gate-drain charge | Q_{GD} | | - | 6.4 | - | |
| Turn on delay time | $t_{d(on)}$ | $V_{DD}=250V, I_D=8.0A, R_G=25\Omega$ | - | 18 | - | ns |
| Rise time | t_r | | - | 65 | - | |
| Turn off delay time | $t_{d(off)}$ | | - | 93 | - | |
| Fall time | t_f | | - | 64 | - | |




Body Diode(Source – Drain) Electrical Characteristics (T_j = 25°C)

| Parameter | Symbol | Test Condition | Value | | | Units |
|--|-----------------|---|-------|------|------|-------|
| | | | Min | Typ | Max | |
| Continuous diode forward current | I _S | - | - | - | 8.0 | A |
| Maximum pulsed drain to source diode forward current | I _{SM} | - | - | - | 32.0 | A |
| Forward voltage | V _{SD} | I _{SD} =8.0A, V _{GS} =0V | - | - | 1.4 | V |
| Reverse recovery time | t _{rr} | I _{SD} =8.0A, V _{GS} =0V di/dt=100A/μs | - | 335 | - | ns |
| Reverse recovery charge | Q _{rr} | | - | 2.95 | - | uC |

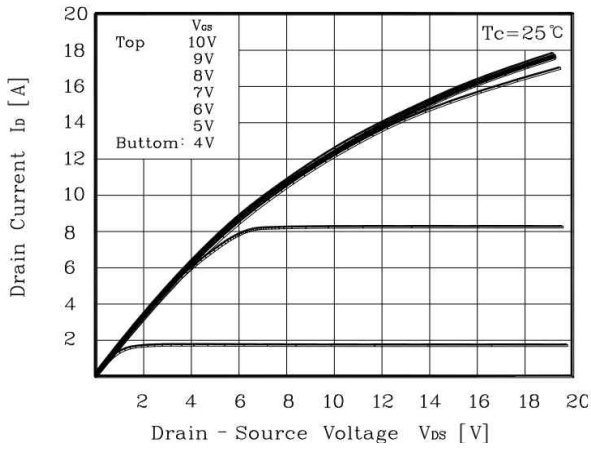

Thermal Characteristics(T_C = 25°C)

| Symbol | Parameter | Typ | Max | Units |
|----------------------|------------------|-----|------|-------|
| R _{th(j-c)} | Junction to case | - | 3.12 | °C/W |

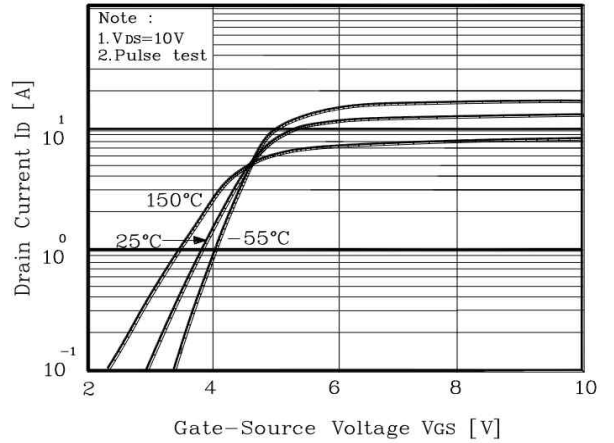


Typical Electrical Characteristics Curves (T_j = 25°C)

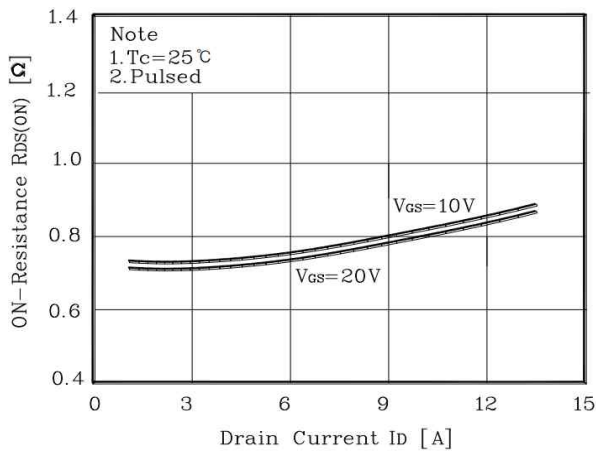
V_{DS} – I_D Characteristics



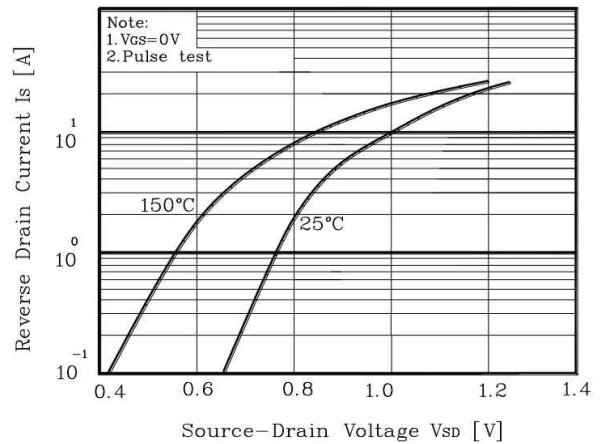
V_{GS} – I_D Characteristics



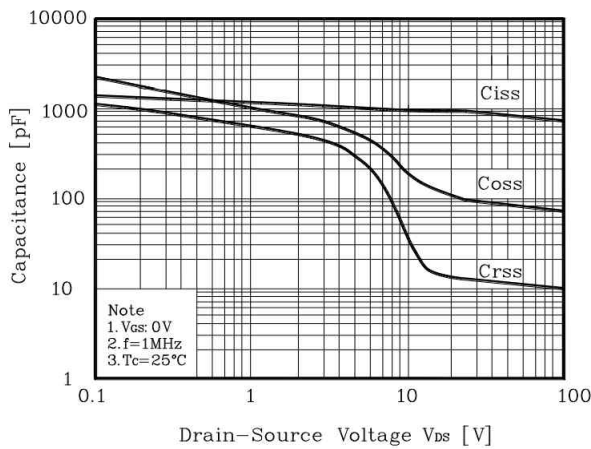
I_D – R_{DS(on)} Characteristics



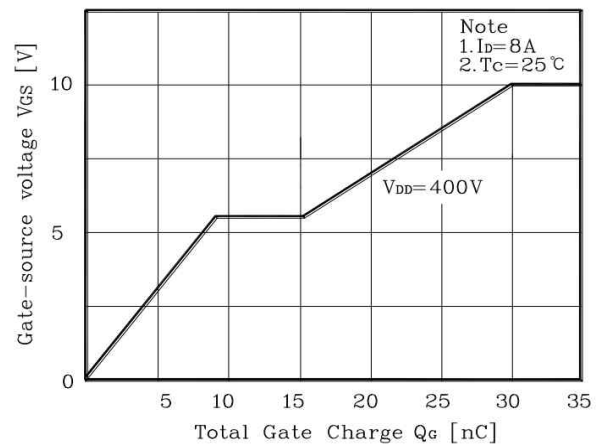
V_{SD} – I_S Characteristics



V_{DS} – C_T Characteristics

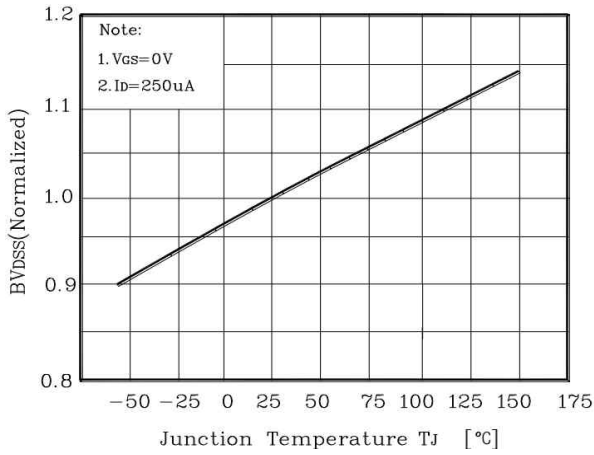


Q_g – V_{GS} Characteristics

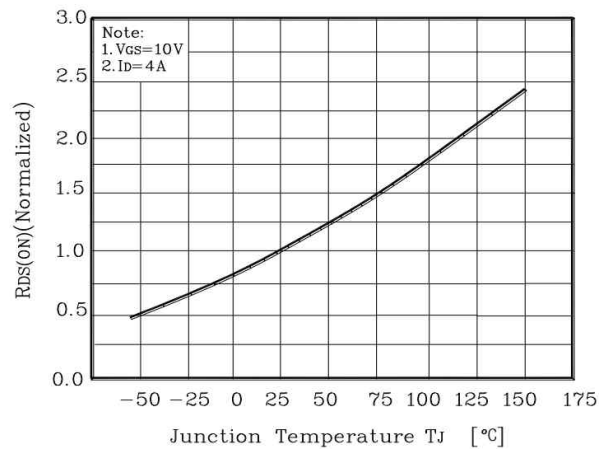


Typical Electrical Characteristics Curves ($T_j = 25^\circ\text{C}$)

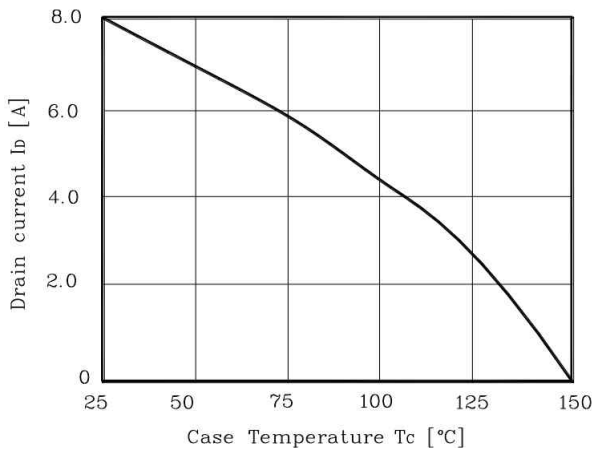
$T_j - V_{DSS}(\text{Normalized})$ Characteristics



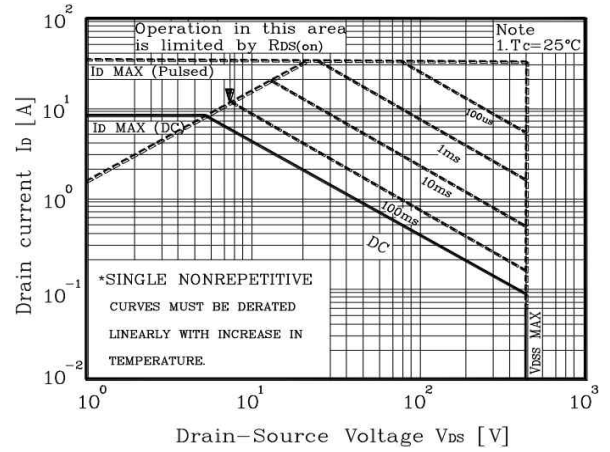
$T_j - R_{DS(on)}(\text{Normalized})$ Characteristics



$T_c - I_D$ Characteristics



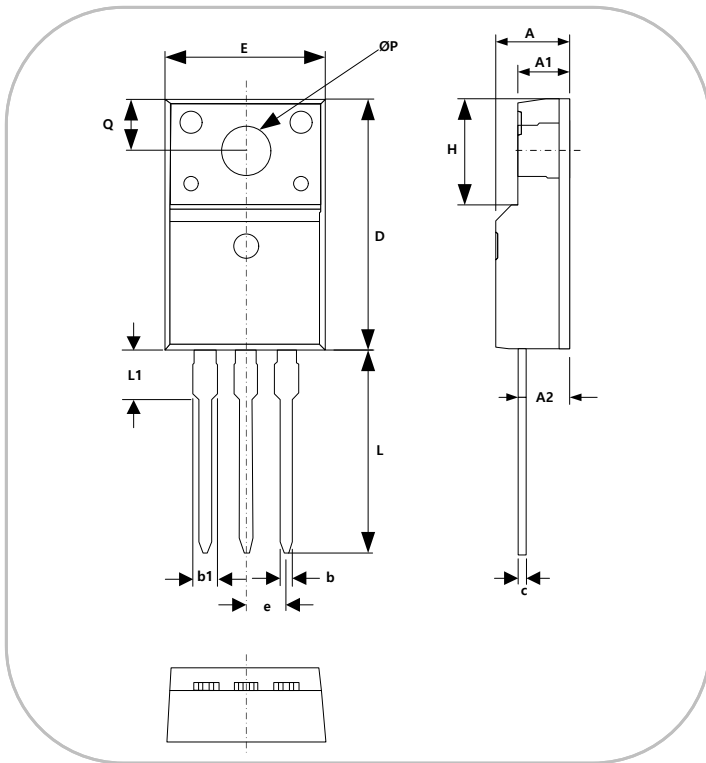
SOA Characteristics



Package Dimensions(TO-220F-3L)

[Unit : mm]

| SYMBOL | MIN | MAX |
|--------|----------|-------|
| A | 4.50 | 4.90 |
| A1 | 2.34 | 2.74 |
| A2 | 2.56 | 2.96 |
| b | 0.70 | 0.90 |
| b1 | 1.27 | 1.47 |
| c | 0.45 | 0.60 |
| D | 15.67 | 16.07 |
| E | 9.96 | 10.36 |
| e | 2.54 BSC | |
| H | 6.48 | 6.88 |
| L | 12.68 | 13.28 |
| L1 | 3.03 | 3.43 |
| φP | 3.08 | 3.28 |
| Q | 3.20 | 3.40 |



Marking Information

